HMC129* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC129G8 Evaluation Board.
- HMC129LC4 Evaluation Board

DOCUMENTATION

Data Sheet

- HMC129 Die Data Sheet
- HMC129G8 Data Sheet
- HMC129LC4 Data Sheet

TOOLS AND SIMULATIONS

- HMC129 S-Parameter
- HMC129G8 S-Parameters
- HMC129LC4 S-Parameters

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: LC4, LC4B (QTR: 2014-00380 REV: 01)
- Semiconductor Qualification Test Report: MESFET-B (QTR: 2013-00245)

DESIGN RESOURCES

- HMC129 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC129 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

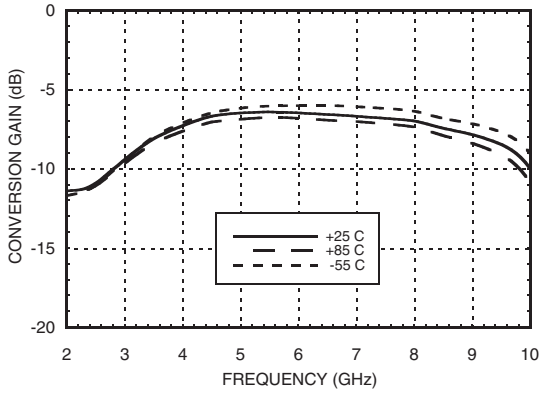
TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

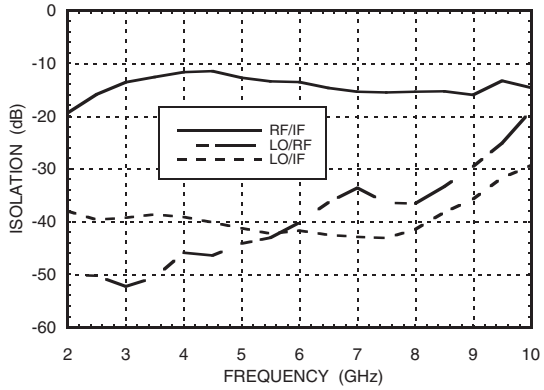
DOCUMENT FEEDBACK

Submit feedback for this data sheet.

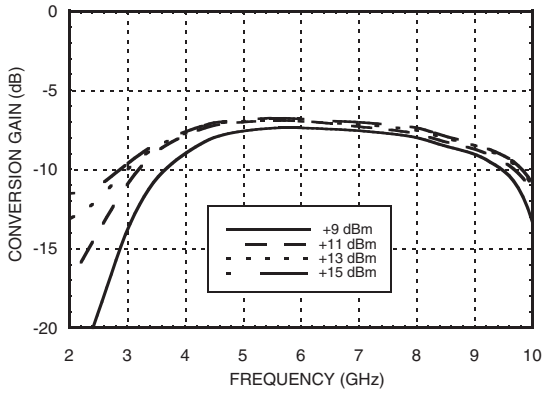
Conversion Gain vs. Temperature LO = +15 dBm



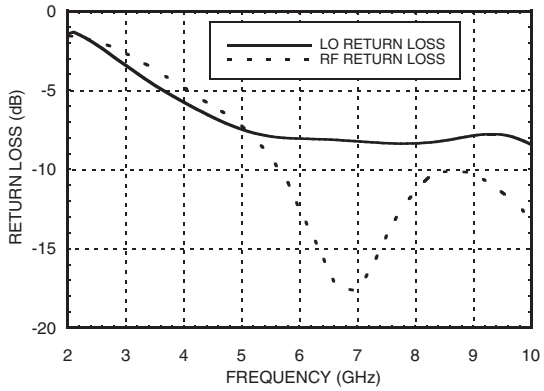
Isolation @ LO = +15 dBm



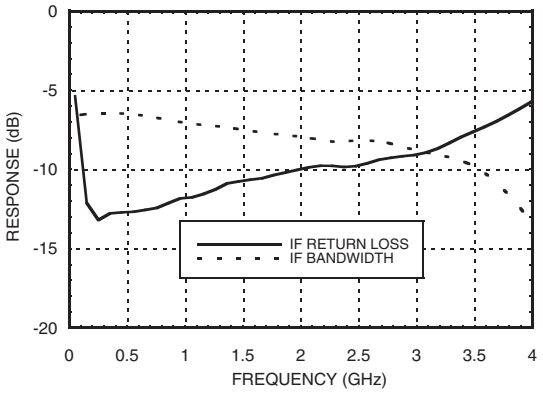
Conversion Gain vs. LO Drive



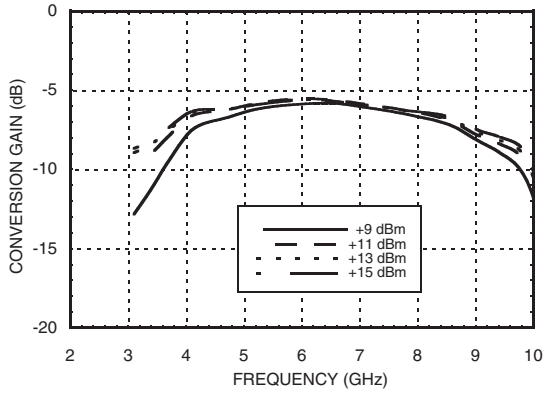
Return Loss @ LO = +15 dBm



IF Bandwidth @ LO = +15 dBm



Unconverter Performance Conversion Gain vs. LO Drive



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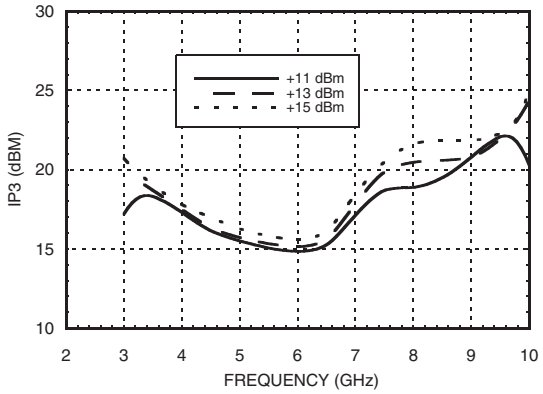
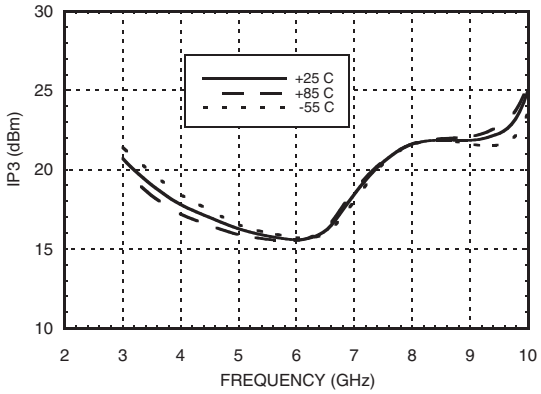
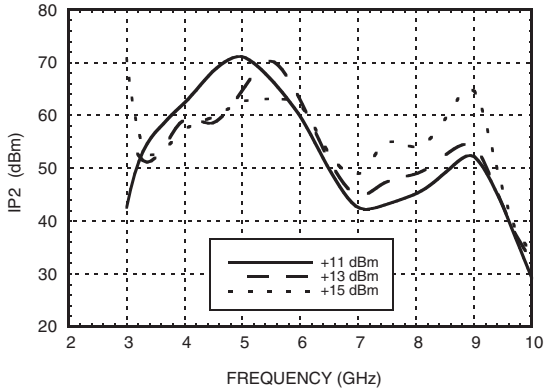
Input IP3 vs. LO Drive



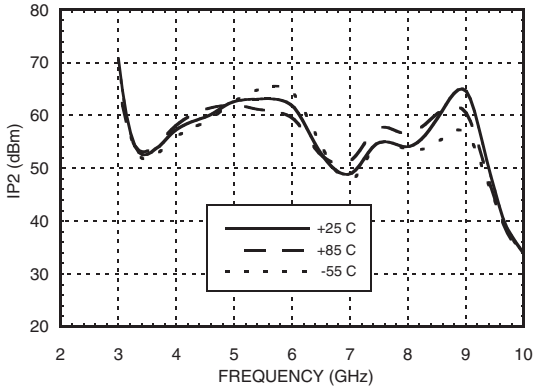
Input IP3 vs. Temperature @ LO = +15 dBm



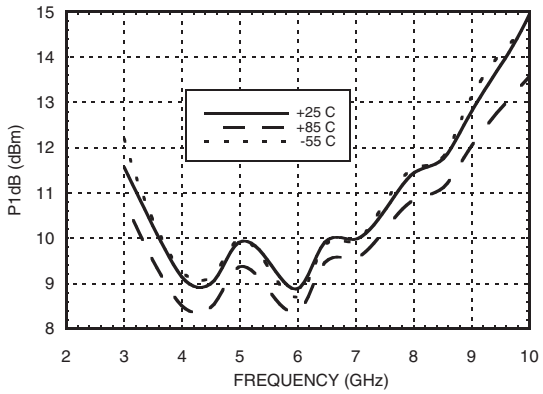
Input IP2 vs. LO Drive



Input IP2 vs. Temperature @ LO = +15 dBm



Input P1dB vs. Temperature @ LO = +15 dBm



Harmonics of LO

	nLO Spur @ RF Port			
LO Freq. (GHz)	1	2	3	4
4	-30.7	-33.5	-32.7	-56.7
5	-29.2	-57.3	-64.8	-43.8
6	-24.7	-41.8	-35.0	-43.0
7	-19.7	-42.5	-20.5	-45.7
8	-23.3	-45.7	-22.5	-46.8
9	-17.2	-36.8	-26.7	-68.7

LO = +13 dBm
All values in dBc below input LO level measured at RF port

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MxN Spurious @ IF Port

	nLO				
mRF	0	1	2	3	4
0	xx	13.66	26.83	9.16	38.33
1	8.16	0	31.33	49.33	43.5
2	78.5	80.16	75.16	79.16	76.66
3	76.0	80.0	81.16	64.5	78.66
4	73.83	77.83	80.0	81.83	82.0

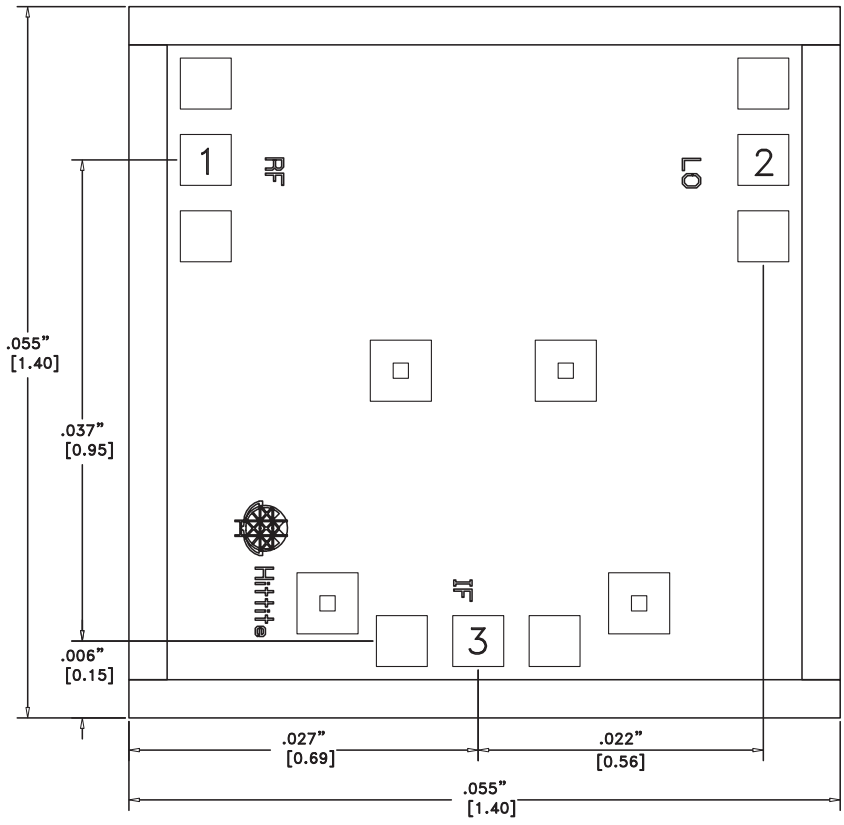
RF Freq. = 6.1 GHz @ -10 dBm
LO Freq. = 6.0 GHz @ +13 dBm
Measured as downconverter

Absolute Maximum Ratings

LO Drive	+27 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Die Packaging Information [1]

Standard	Alternate
WP-3 (Waffle Pack)	[2]

[1] Refer to the "Packaging Information" section for die packaging dimensions.
[2] For alternate packaging information contact Hittite Microwave Corporation.

NOTES:
1. ALL DIMENSIONS ARE IN INCHES [MM]
2. BOND PADS ARE .004" SQUARE
3. TYPICAL BOND PAD SPACING CENTER TO CENTER .1 IS .006" EXCEPT AS SHOWN
4. DIE THICKNESS = .004" [.100 MM]
5. BACKSIDE METALIZATION: GOLD
6. BACKSIDE METAL IS GROUND
7. BOND PAD METALIZATION: GOLD

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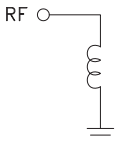
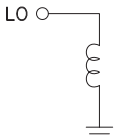
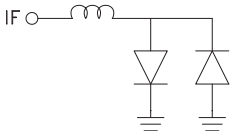
Pad Descriptions

Pad Number	Function	Description	Interface Schematic
1	RF	This pin is DC coupled and matched to 50 Ohms.	
2	LO	This pin is DC coupled and matched to 50 Ohms.	
3	IF	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC this pin must not source or sink more than 2mA of current or die non-function and possible die failure will result.	
	GND	The backside of the die must connect to RF ground.	

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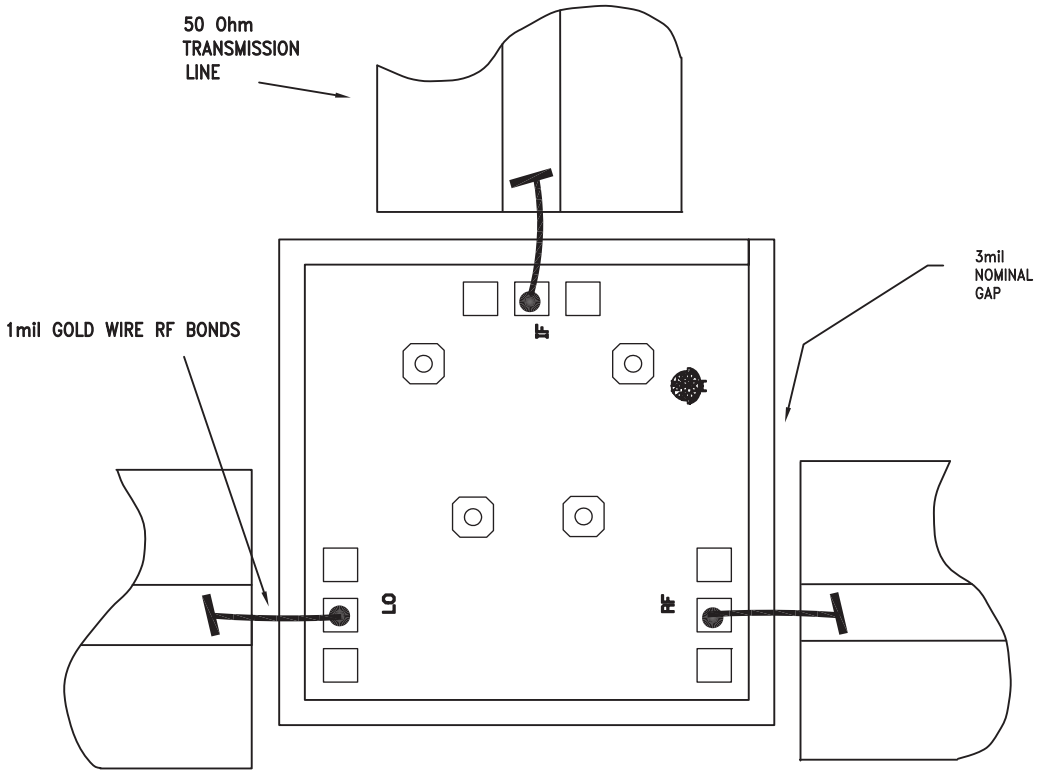
Assembly Diagram



Handling Precautions

Follow these precautions to avoid permanent damage.

Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.
Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.
Static Sensitivity: Follow ESD precautions to protect against ESD strikes.
Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.
General Handling: Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers. The surface of the chip has fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.

Mounting

The chip is back-metallized and can be die mounted with AuSn eutectic preforms or with electrically conductive epoxy. The mounting surface should be clean and flat.

Eutectic Die Attach: A 80/20 gold tin preform is recommended with a work surface temperature of 255 °C and a tool temperature of 265 °C. When hot 90/10 nitrogen/hydrogen gas is applied, tool tip temperature should be 290 °C. DO NOT expose the chip to a temperature greater than 320 °C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.
Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer's schedule.

Wire Bonding

Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

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